

## High Current Axial Plastic Rectifier

### Major Ratings and Characteristics

$I_{F(AV)}$	6.0 A
$V_{RRM}$	50 V to 800 V
$I_{FSM}$	400 A
$V_F$	0.9 V, 0.95 V
$I_R$	5.0 $\mu$ A
$T_j$ max.	150 °C



**Case Style P600**

### Features

- Low forward voltage drop
- Low leakage current,  $I_R$  less than 0.1  $\mu$ A
- High forward current capability
- High forward surge capability

### Typical Applications

For use in general purpose rectification of power supplies, inverters, converters and freewheeling diodes application. (Note: These devices are not Q101 qualified. Therefore, the devices specified in this datasheet have not been designed for use in automotive or Hi-Rel applications.)

### Maximum Ratings

( $T_A = 25$  °C unless otherwise noted)

Parameter	Symbol	GI750	GI751	GI752	GI754	GI756	GI758	Unit
Maximum repetitive peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	V
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	V
Maximum non-repetitive peak reverse voltage	$V_{RSM}$	60	120	240	480	720	1200	V
Maximum average forward rectified current at $T_A = 60$ °C, P.C.B. mounting (fig. 1) $T_L = 60$ °C, 0.125" (3.18 mm) lead length (fig. 2)	$I_{F(AV)}$	6.0 22						A
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	$I_{FSM}$	400						A
Operating junction and storage temperature range	$T_J, T_{STG}$	- 50 to + 150						°C

### Mechanical Data

**Case:** P600, void-free molded plastic body

Epoxy meets UL-94V-0 Flammability rating

**Terminals:** Matte tin plated (E3 Suffix) leads, solderable per J-STD-002B and MIL-STD-750, Method 2026

**Polarity:** Color band denotes cathode end

# GI750 thru GI758

Vishay Semiconductors



## Electrical Characteristics

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Parameter	Test condition	Symbol	GI750	GI751	GI752	GI754	GI756	GI758	Unit
Maximum instantaneous forward voltage at: 100 A		$V_F$		0.90		0.95		1.30	V
1.25									
Maximum DC reverse current at rated DC blocking voltage	$T_A = 25^\circ\text{C}$ $T_A = 100^\circ\text{C}$	$I_R$		5.0		1.0			$\mu\text{A}$ mA
Typical reverse recovery time	at $I_F = 0.5 \text{ A}$ , $I_R = 1.0 \text{ A}$ , $I_{rr} = 0.25 \text{ A}$	$t_{rr}$		2.5					$\mu\text{s}$
Typical junction capacitance	at 4.0 V, 1 MHz	$C_J$		150					pF

## Thermal Characteristics

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

Parameter	Symbol	GI750	GI751	GI752	GI754	GI756	GI758	Unit
Typical thermal resistance <sup>(1)</sup>	$R_{\theta JA}$ $R_{\theta JL}$		20		4.0			$^\circ\text{C/W}$

Notes:

(1) Thermal resistance from junction to ambient and from junction to lead at 0.375" (9.5 mm) lead length, P.C.B. mounted with 1.1" x 1.1" (30 x 30 mm) copper pads

## Ratings and Characteristics Curves

( $T_A = 25^\circ\text{C}$  unless otherwise noted)

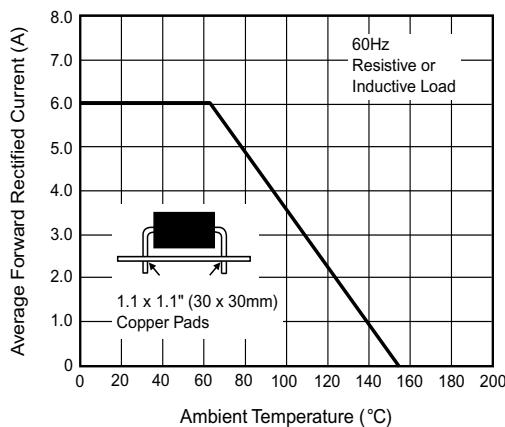


Figure 1. Maximum Forward Current Derating Curve

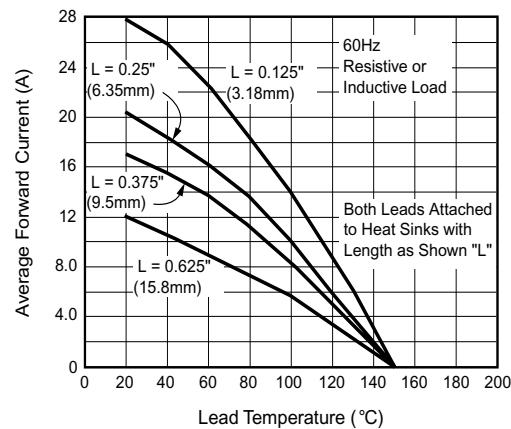
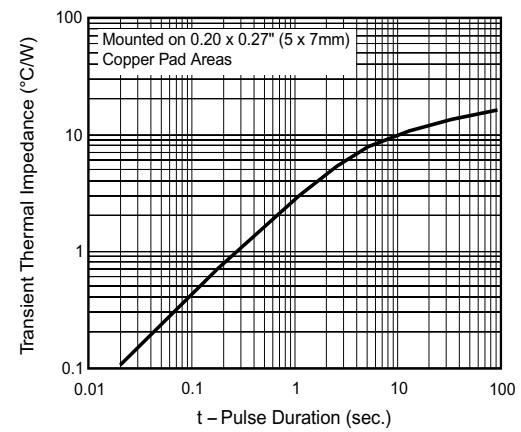
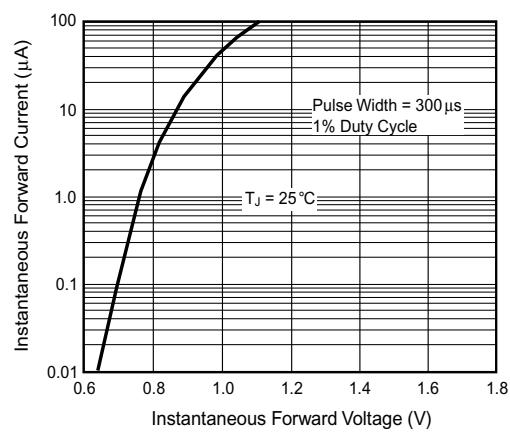
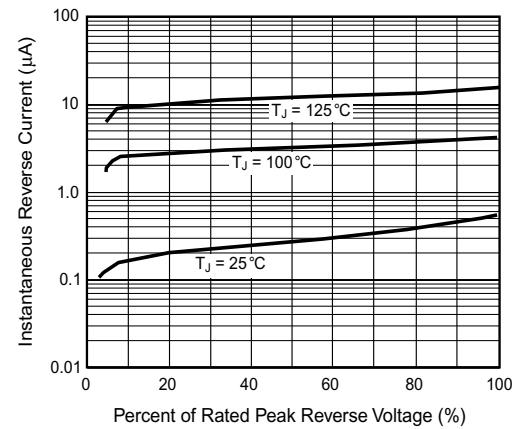
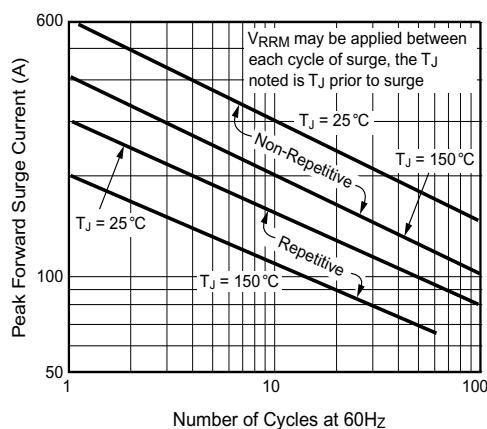


Figure 2. Maximum Forward Current Derating Curve



### Package outline dimensions in inches (millimeters)

